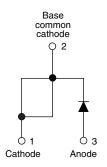
Vishay Semiconductors

Fast Soft Recovery Rectifier Diode, 40 A







PRODUCT SUMMARY						
Package	TO-247AC modified (2 pins)					
I _{F(AV)}	40 A					
V_{R}	1000 V, 1200 V					
V _F at I _F	1.4 V					
I _{FSM}	475 A					
t _{rr}	95 ns					
T _J max.	150 °C					
Diode variation	Single die					
Snap factor	0.5					

FEATURES

- 150 °C max. operating junction temperature
- Low forward voltage drop and short reverse recovery time
- Designed and qualified according to JEDEC-JESD47
- Material categorization:
 For definitions of compliance please see www.vishav.com/doc?99912





COMPLIANT
HALOGEN

APPLICATIONS

These devices are intended for use in output rectification and freewheeling in inverters, choppers and converters as well as in input rectification where severe restrictions on conducted EMI should be met.

DESCRIPTION

The VS-40EPF1... fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
V _{RRM}		1000/1200	V				
I _{F(AV)}	Sinusoidal waveform	40	^				
I _{FSM}		475	А				
t _{rr}	1 A, 100 A/µs	95	ns				
V _F	20 A, T _J = 25 °C	1.25	V				
T _J		- 40 to 150	°C				

VOLTAGE RATINGS							
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA				
VS-40EPF10PbF, VS-40EPF10-M3	1000	1100	10				
VS-40EPF12PbF, VS-40EPF12-M3	1200	1300	10				

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum average forward current	I _{F(AV)}	T _C = 105 °C, 180° conduction half sine wave	40			
Maximum peak one cycle	I _{FSM}	10 ms sine pulse, rated V _{RRM} applied 400		Α		
non-repetitive surge current		10 ms sine pulse, no voltage reapplied	475			
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V _{RRM} applied	800	A ² s		
Maximum I-t for fusing	1-1	10 ms sine pulse, no voltage reapplied 1131		A-5		
Maximum I ² √t for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied	11 310	A²√s		



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ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS		
Maximum forward voltage drop	V_{FM}	40 A, T _J = 25 °C		1.4	V		
Forward slope resistance	r _t	T _{.1} = 150 °C		6.82	mΩ		
Threshold voltage	V _{F(TO)}	1 1J = 150 C		0.94	V		
Maximum various lackage arrest		T _J = 25 °C	V Dated V	0.1	mA		
Maximum reverse leakage current	I _{RM}	T _J = 150 °C	V_R = Rated V_{RRM}	10	IIIA		

RECOVERY CHARACTERISTICS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Reverse recovery time	t _{rr}	In at 10 Anu	450	ns	I _{FM} t	
Reverse recovery current	I _{rr}	I _F at 10 A _{pk} 25 A/μs	6	Α		
Reverse recovery charge	Q _{rr}	25 °C	1.8	μC	dir/ dt Q _{rr}	
Snap factor	S		0.5		I _{RM(REC)}	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and stor temperature range	age	T _J , T _{Stg}		- 40 to 150	°C	
Maximum thermal resistant junction to case	e,	R_{thJC}	DC operation	0.6		
Maximum thermal resistant junction to ambient	e,	R _{thJA}		40	°C/W	
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.2		
Approximate weight				6	g	
Approximate weight				0.21	OZ.	
May ation toward	minimum			6 (5)	kgf ⋅ cm	
Mounting torque maximum				12 (10)	(lbf ⋅ in)	
Maulina davia			One at the TO 04740 and different (IEDEO)	40EP	F10	
Marking device			Case style TO-247AC modified (JEDEC)	40EPF12		

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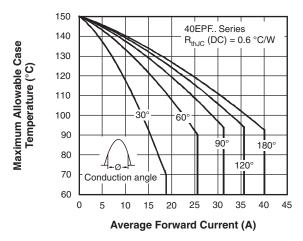


Fig. 1 - Current Rating Characteristics

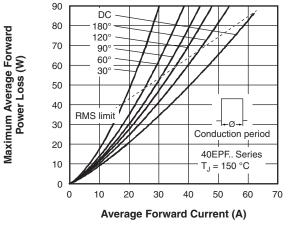


Fig. 4 - Forward Power Loss Characteristics

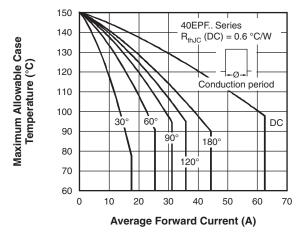


Fig. 2 - Current Rating Characteristics

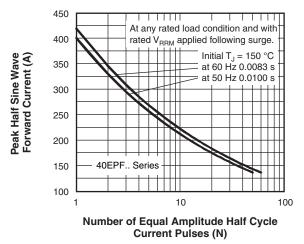


Fig. 5 - Maximum Non-Repetitive Surge Current

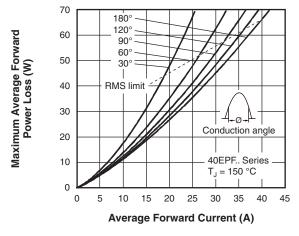


Fig. 3 - Forward Power Loss Characteristics

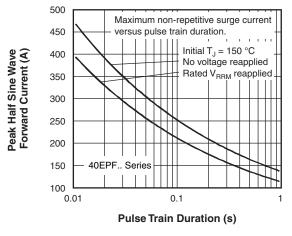


Fig. 6 - Maximum Non-Repetitive Surge Current

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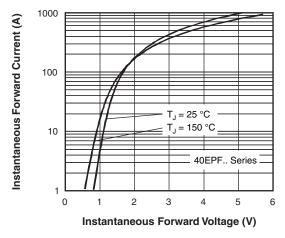


Fig. 7 - Forward Voltage Drop Characteristics

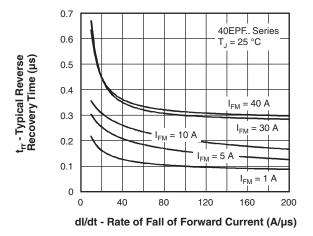


Fig. 8 - Recovery Time Characteristics, T_J = 25 °C

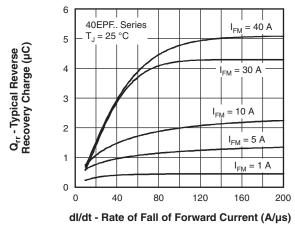


Fig. 10 - Recovery Charge Characteristics, $T_J = 25 \, ^{\circ}\text{C}$

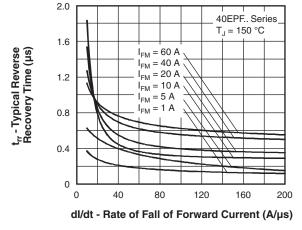


Fig. 9 - Recovery Time Characteristics, T_J = 150 °C

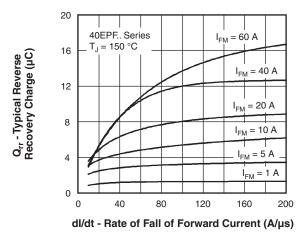


Fig. 11 - Recovery Charge Characteristics, $T_J = 150 \, ^{\circ}\text{C}$



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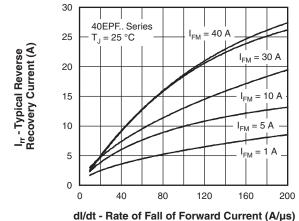


Fig. 12 - Recovery Current Characteristics, T_J = 25 °C

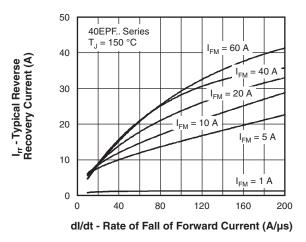


Fig. 13 - Recovery Current Characteristics, T_J = 150 °C

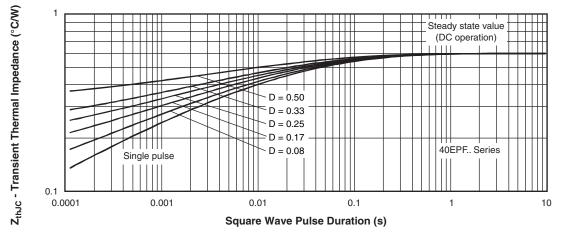
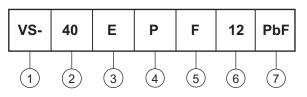


Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

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ORDERING INFORMATION TABLE





- 1 Vishay Semiconductors product
- Current rating (40 = 40 A)
- Gircuit configuration:

 E = Single diode
- 4 Package:

P = TO-247AC modified

5 - Type of silicon:

F = Fast recovery

6 - Voltage code x 100 = V_{RRM} 10 = 1000 V 12 = 1200 V

7 - Environmental digit:

- PbF = Lead (Pb)-free and RoHS compliant
- -M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free

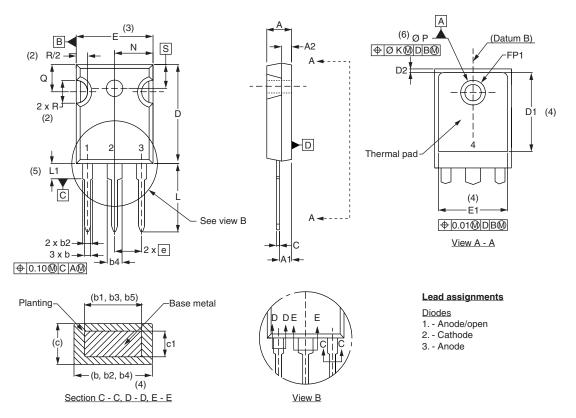
ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-40EPF10PbF	25	500	Antistatic plastic tubes					
VS-40EPF10-M3	25	500	Antistatic plastic tubes					
VS-40EPF12PbF	25	500	Antistatic plastic tubes					
VS-40EPF12-M3	25	500	Antistatic plastic tubes					

LINKS TO RELATED DOCUMENTS						
Dimensions <u>www.vishay.com/doc?95253</u>						
Part marking information	TO-247AC modified PbF	www.vishay.com/doc?95255				
Part marking information	TO-247AC modified -M3	www.vishay.com/doc?95442				



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DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.37	0.065	0.094	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
С	0.38	0.86	0.015	0.034	
c1	0.38	0.76	0.015	0.030	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.72	-	0.540	-	
е	5.46	BSC	0.215	BSC	
FK	2.	54	0.0	010	
L	14.20	16.10	0.559	0.634	
L1	3.71	4.29	0.146	0.169	
N	7.62	BSC	0.3		
ΦР	3.56	3.66	0.14	0.144	
ФР1	1	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	1.78	0.216	
S	5.51	BSC	0.217	'BSC	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC outline TO-247 with exception of dimension c



Legal Disclaimer Notice

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Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

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